Small Signal MOSFET

60 V, 310 mA, Single, N-Channel, SOT-23

Features

- Low R_{DS(on)}
- Small Footprint Surface Mount Package
- Trench Technology
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Low Side Load Switch
- Level Shift Circuits
- DC-DC Converter
- Portable Applications i.e. DSC, PDA, Cell Phone, etc.

MAXIMUM RATINGS (T_J = 25°C unless otherwise stated)

Rating		Symbol	Value	Unit
Drain-to-Source Voltage	V _{DSS}	60	V	
Gate-to-Source Voltage		V _{GS}	±30	V
Drain Current (Note 1) Steady State t < 5 s	$T_{A} = 25^{\circ}C$ $T_{A} = 85^{\circ}C$ $T_{A} = 25^{\circ}C$ $T_{A} = 85^{\circ}C$	I _D	260 190 310 220	mA
Power Dissipation (Note 1) Steady State t < 5 s		P _D	300 420	mW
Pulsed Drain Current (t _p = 10 μs)		I _{DM}	1.2	Α
Operating Junction and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C
Source Current (Body Diode)	Is	300	mA	
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)		TL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 1)	$R_{ heta JA}$	417	°C/W
Junction-to-Ambient – $t \le 5$ s (Note 1)	$R_{\theta JA}$	300	

^{1.} Surface-mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [1 oz] including traces)



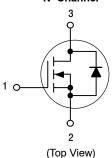
ON Semiconductor®

http://onsemi.com

V _{(BR)DSS}	R _{DS(on)} MAX	I _D MAX (Note 1)	
60 V	3.0 Ω @ 4.5 V	310 mA	
	2.5 Ω @ 10 V		

Simplified Schematic

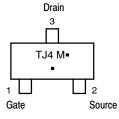
N-Channel



MARKING DIAGRAM & PIN ASSIGNMENT



SOT-23 **CASE 318** STYLE 21



TJ4 = Device Code = Date Code М = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
NTR5103NT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel

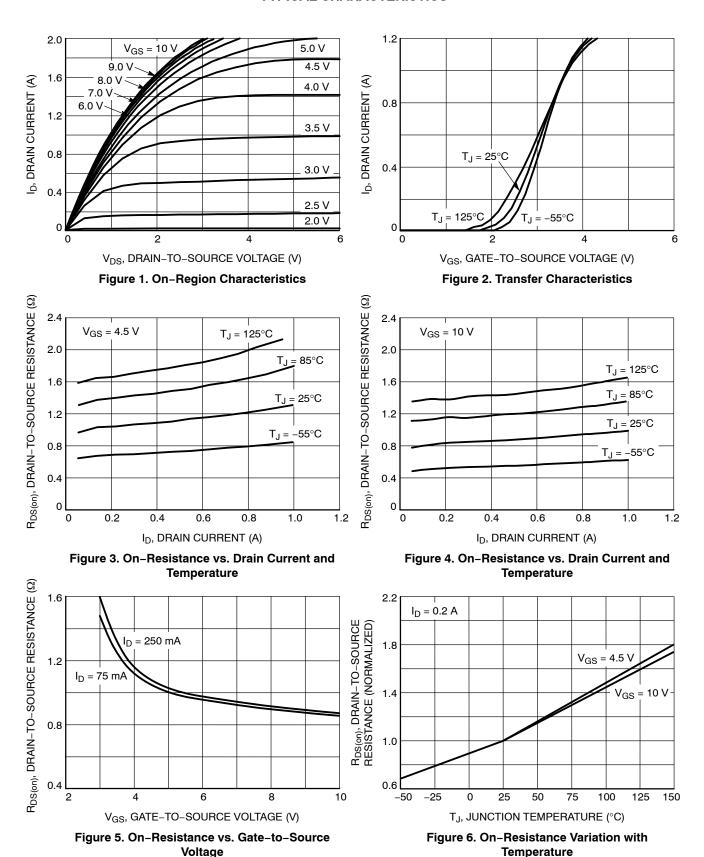
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Test Co	ndition	Min	Тур	Max	Units
OFF CHARACTERISTICS	•	•					
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		60			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J				75		mV/°C
Zero Gate Voltage Drain Current		V _{GS} = 0 V,	0 V, T _J = 25°C			1	μΑ
		V _{DS} = 60 V	T _J = 125°C			500	1
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V _{GS} = ±30 V				200	nA
ON CHARACTERISTICS (Note 2)				•		•	•
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}$	I _D = 250 μA	1.9		2.6	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J				4.4		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V, I _D = 240 mA			1.0	2.5	Ω
		V _{GS} = 4.5 V, I _D = 50 mA			1.4	3.0	
Forward Transconductance	9FS	V _{DS} = 5 V, I _D = 200 mA			530		mS
CHARGES AND CAPACITANCES				•		•	•
Input Capacitance	C _{ISS}	$V_{GS} = 0 \text{ V, f} = 1 \text{ MHz,}$ $V_{DS} = 25 \text{ V}$			26.7	40	pF
Output Capacitance	C _{OSS}				4.6		
Reverse Transfer Capacitance	C _{RSS}				2.9		
Total Gate Charge	Q _{G(TOT)}				0.81		nC
Threshold Gate Charge	Q _{G(TH)}	V _{GS} = 5 V,	V _{DS} = 10 V;		0.31		
Gate-to-Source Charge	Q_{GS}	I _D = 2	40 mA		0.48		
Gate-to-Drain Charge	Q_{GD}				0.08		
SWITCHING CHARACTERISTICS, V _{GS}	= V (Note 3)			•		•	•
Turn-On Delay Time	t _{d(ON)}				1.7		ns
Rise Time	t _r	V_{GS} = 10 V, V_{DD} = 30 V, I_{D} = 200 mA, R_{G} = 10 Ω			1.2		
Turn-Off Delay Time	t _{d(OFF)}				4.8		
Fall Time	t _f				3.6		
DRAIN-SOURCE DIODE CHARACTER	ISTICS	•		-	-	-	-
Forward Diode Voltage	V _{SD}	V _{GS} = 0 V,	T _J = 25°C		0.79	1.2	V
		I _S = 200 mA	T _J = 85°C		0.7		1

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Pulse Test: pulse width $\leq 300~\mu s$, duty cycle $\leq 2\%$ 3. Switching characteristics are independent of operating junction temperatures

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

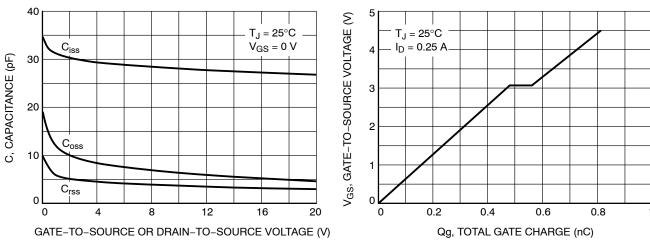


Figure 7. Capacitance Variation

Figure 8. Gate-to-Source and Drain-to-Source Voltage vs. Total Charge

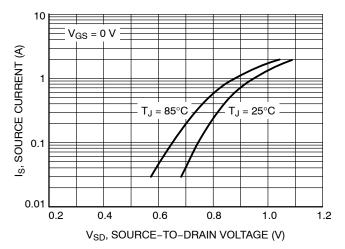
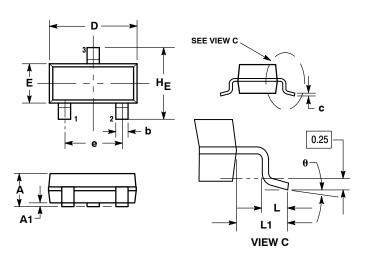


Figure 9. Diode Forward Voltage vs. Current

PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AP**



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH,
- PROTRUSIONS, OR GATE BURRS

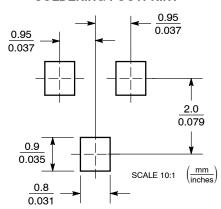
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104
θ	0°		10°	0°		10°

STYLE 21:

PIN 1. GATE

- SOURCE 2.
- DRAIN

SOLDERING FOOTPRINT



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